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# **NCE0115K**

### NCE N-Channel Enhancement Mode Power MOSFET

### **Description**

The NCE0115K uses advanced trench technology and design to provide excellent R<sub>DS(ON)</sub> with low gate charge. It can be used in a wide variety of applications.

#### **General Features**

V<sub>DS</sub> =100V,I<sub>D</sub> =15A

 $R_{DS(ON)} < 90 \text{m}\Omega$  @  $V_{GS} = 10 \text{V}$  (Typ:75m $\Omega$ )  $R_{DS(ON)}$  < 100m $\Omega$  @  $V_{GS}$ =4.5V (Typ:80m $\Omega$ )

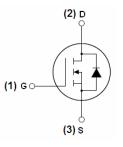
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high EAS
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

### **Application**

- Power switching application
- Hard switched and high frequency circuits

100% UIS TESTED!

100% AVds TESTED!



#### Schematic diagram



Marking and pin assignment



TO-252-2L top view

### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE0115K	NCE0115K	TO-252-2L	-	-	-

### Absolute Maximum Ratings (T<sub>C</sub>=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	100	V
Gate-Source Voltage	V <sub>G</sub> S	±20	V
Drain Current-Continuous	I <sub>D</sub>	15	А
Drain Current-Continuous(T <sub>C</sub> =100°C)	I <sub>D</sub> (100°C)	10.6	Α
Pulsed Drain Current	I <sub>DM</sub>	60	Α
Maximum Power Dissipation	P <sub>D</sub>	50	W
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	16	mJ
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 175	$^{\circ}\!\mathbb{C}$



# NCE0115K

### **Thermal Characteristic**

Thermal Resistance, Junction-to-Case (Note 2)	$R_{ heta JC}$	3	°C/W	
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Electrical Characteristics (T<sub>C</sub>=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit	
Off Characteristics	·						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA 10		110	-	V	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =100V,V <sub>GS</sub> =0V	-	-	1	μΑ	
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA	
On Characteristics (Note 3)	·						
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	1.0	1.6	2.5	V	
Drain-Source On-State Resistance	В	V <sub>GS</sub> =10V, I <sub>D</sub> =10A	-	75	90	mΩ	
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =10A	-	80	100		
Forward Transconductance	<b>G</b> FS	V <sub>DS</sub> =5V,I <sub>D</sub> =10A	-	10	-	S	
Dynamic Characteristics (Note4)							
Input Capacitance	C <sub>lss</sub>		-	830	-	PF	
Output Capacitance	Coss	$V_{DS}$ =50 $V$ , $V_{GS}$ =0 $V$ ,	-	44.2	-	PF	
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0MHz	-	30.1	-	PF	
Switching Characteristics (Note 4)						<u>l</u>	
Turn-on Delay Time	t <sub>d(on)</sub>		-	15	-	nS	
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =50 $V$ , $R_L$ =6. $4\Omega$	-	5	-	nS	
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10 $V$ , $R_{G}$ =3 $\Omega$	-	25	-	nS	
Turn-Off Fall Time	t <sub>f</sub>		-	7	-	nS	
Total Gate Charge	Qg		-	22.3		nC	
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}=50V, I_{D}=10A,$	-	2.87	-	nC	
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =10V	-	6.14	-	nC	
Drain-Source Diode Characteristics	<u> </u>		1				
Diode Forward Voltage (Note 3)	$V_{SD}$	V <sub>GS</sub> =0V,I <sub>S</sub> =15A	-	-	1.2	V	
Diode Forward Current (Note 2)	Is		-	-	15	Α	

### Notes:

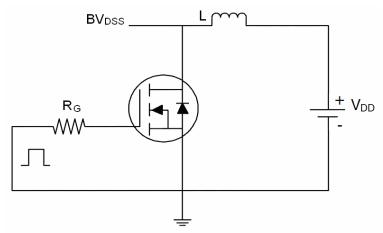
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production



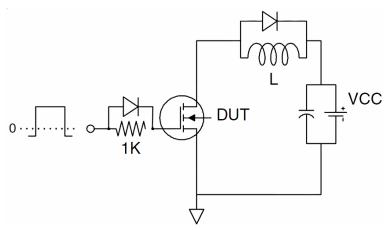
# NCE0115K

### **Test Circuit**

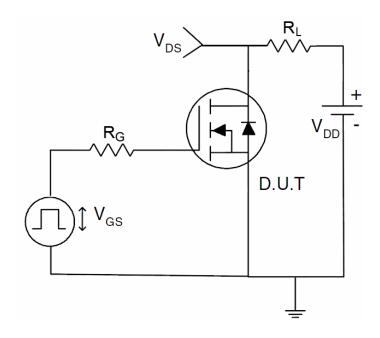
### 1) E<sub>AS</sub> test Circuit



### 2) Gate charge test Circuit



### 3) Switch Time Test Circuit

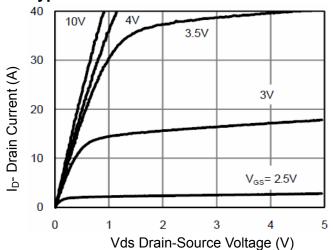


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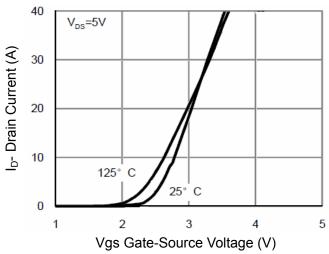


## **NCE0115K**

### Typical Electrical and Thermal Characteristics (Curves)



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

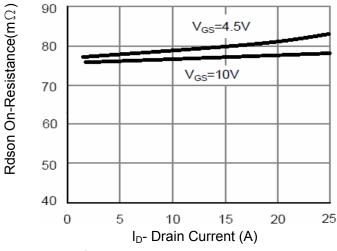


Figure 3 Rdson- Drain Current

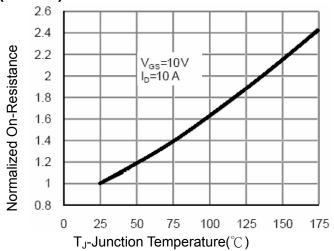


Figure 4 Rdson-JunctionTemperature

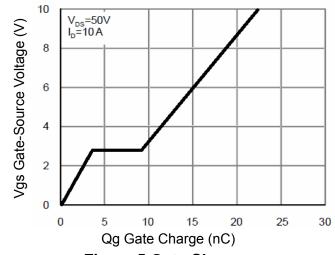


Figure 5 Gate Charge

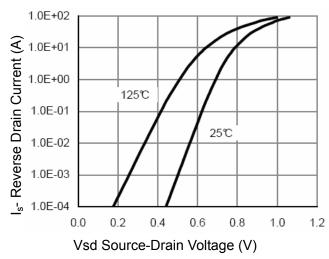


Figure 6 Source- Drain Diode Forward



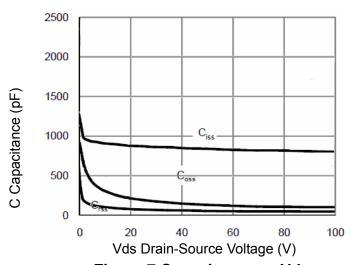


Figure 7 Capacitance vs Vds

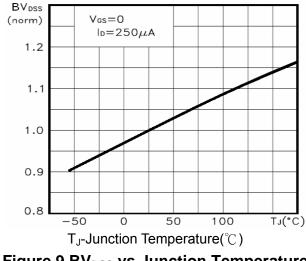
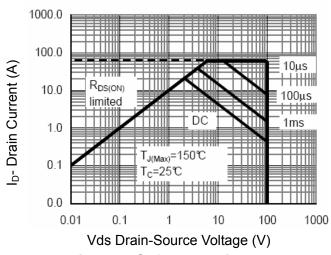


Figure 9 BV<sub>DSS</sub> vs Junction Temperature



**Figure 8 Safe Operation Area** 

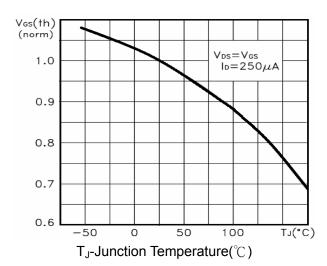
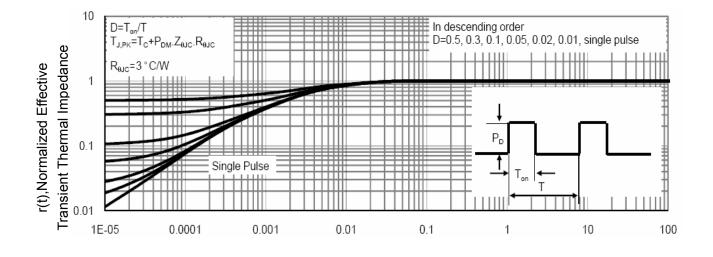


Figure 10 V<sub>GS(th)</sub> vs Junction Temperature



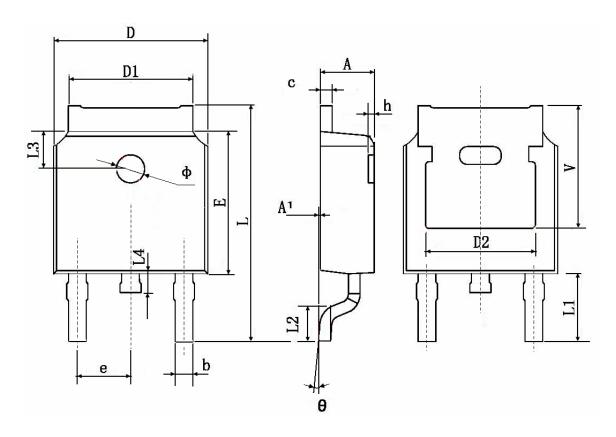
**Figure 11 Normalized Maximum Transient Thermal Impedance** 

Square Wave Pluse Duration(sec)

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## **TO-252 Package Information**



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
	Min.	Max.	Min.	Max.	
А	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
b	0.660	0.860	0.026	0.034	
С	0.460	0.580	0.018	0.023	
D	6.500	6.700	0.256	0.264	
D1	5.100	5.460	0.201	0.215	
D2	4.830	TYP.	0.190 TYP.		
Е	6.000	6.200	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.800	10.400	0.386	0.409	
L1	2.900	2.900 TYP.		TYP.	
L2	1.400	1.700	0.055	0.067	
L3	1.600	TYP.	0.063	TYP.	
L4	0.600	1.000	0.024	0.039	
Ф	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
h	0.000	0.300	0.000	0.012	
V	5.350	TYP.	0.211 TYP.		



### http://www.ncepower.com

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